

## **Application Data Sheet**

### **Application Information**

Application Type::	Regular
Subject Matter::	Utility
Suggested Group Art Unit::	N/A
CD-ROM or CD-R?::	None
Sequence submission?::	None
Computer Readable Form (CRF)?::	No
Title::	MANUFACTURING METHOD OF HIGH RESISTIVITY SILICON SINGLE CRYSTAL
Attorney Docket Number::	474022002600
Request for Early Publication?::	No
Request for Non-Publication?::	No
Total Drawing Sheets::	0
Small Entity?::	No
Petition included?::	No
Secrecy Order in Parent Appl.?::	No

### **Applicant Information**

Applicant Authority Type::	Inventor
Primary Citizenship Country::	Japan
Status::	Full Capacity
Given Name::	Nobumitsu
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City of Residence:	Tokyo
Country of Residence:	Japan
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City of mailing address:	Tokyo
Country of mailing address:	Japan
Postal or Zip Code of mailing address::	105-0023

Applicant Authority Type::  
Primary Citizenship Country:: Japan  
Status:: Full Capacity  
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Family Name:: NISHIKAWA  
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Applicant Authority Type:: Inventor  
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Applicant Authority Type:: Inventor  
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Applicant Authority Type:: Inventor  
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**Correspondence Information**

Correspondence Customer Number:: 25227

**Representative Information**

Representative Customer Number:: 25227

**Foreign Priority Information**

Country::	Application number::	FilingDate::	Priority Claimed::
Japan	2003-115388	April 21, 2003	Yes